

P-Channel Enhancement Mode MOSFET

Features

- $R_{DS(ON)}(a)-10V<55m\Omega(Max)$
- $R_{DS(ON)}$ @-4.5V<75m $\Omega(Max)$
- Super high dense cell design for extremely low R_{DS(ON)}
- Reliable and Rugged
- SOT-23 for Surface Mount Package

Applications

- Power Management
- Portable Equipment and Battery Powered Systems

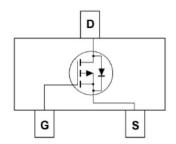


 $BV_{DSS},T_A=25$ °C

-30V

R_{DS(ON)},Max@4.5V

 $75 \mathrm{m}\Omega$



 $I_D, T_A=25$ °C

-4.1A

SOT-23

Absolute Maximum Ratings

T_A=25°C,unless otherwise noted.

Parameter	Symbol	Limit	Unit
Drain-source Voltage	$ m V_{DS}$	-30	V
Gate-source Voltage	V_{GS}	±20	V
Drain Current-Continuous	I_D	-4.1	A
Junction Temperature Range	TJ	-50~+150	°C
Storage Temperature Range	T_{STG}	-50~+150	°C

Electrical Characteristics(T_A=25°C,unless otherwise noted.)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-source breakdown voltage	BV _{DSS}	V _{GS} =0V,I _D =-250μA	-30			V
Drain-source leakage current	I_{DSS}	V _{DS} =-30V,V _{GS} =0V			-1	μΑ
Gate-source leakage current	I_{GSS}	V _{DS} =0V,V _{GS} =±20V			±100	nA
On Characteristics						
Gate Threshold voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_D=-250\mu A$	-1.0		-2.4	V
Drain-source on resistance	R _{DS(on)}	V _{GS} =-10V,I _D =-4.2A			55	mΩ
		V _{GS} =-4.5V,I _D =-4A			75	mΩ
Drain-Source Diode Characteristics						
Diode Forward Voltage	V_{SD}	V _{GS} =0V,I _D =-1A			-1.0	V

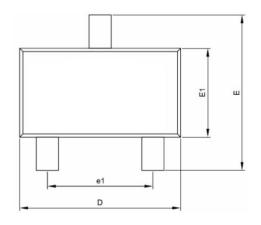
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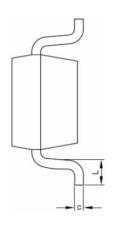


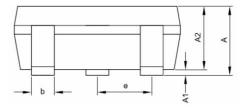
Package Information

SOT-23

Dimensions in mm







Cl1	Dimensisons In Millimeters			
Symbol	MIN	MAX		
A	- 1.12			
A1	0.00	0.10		
A2	0.60	1.02		
D	2.90 BSC			
Е	2.40 BSC			
E1	1.20	1.40		
С	0.08	0.25		
b	0.30	0.50		
e	0.95 BSC			
e1	1.90 BSC			
L	0.20	0.60		

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